



**THE DATASHEET OF
TPCC8002-H(TE12L,Q**



TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (U-MOS -H)

TPCC8002-H

High-Efficiency DC-DC Converter Applications
 Notebook PC Applications
 Portable Equipment Applications

- Small footprint due to a small and thin package
- High-speed switching
- Small gate charge: $Q_{SW} = 7.1 \text{ nC (typ.)}$
- Low drain-source ON-resistance:
 $R_{DS(ON)} = 7.6 \text{ m}\Omega \text{ (typ.) (} V_{GS} = 4.5 \text{ V)}$
- High forward transfer admittance: $|Y_{fs}| = 65 \text{ S (typ.)}$
- Low leakage current: $I_{DSS} = 10 \mu\text{A (max) (} V_{DS} = 30 \text{ V)}$
- Enhancement mode: $V_{th} = 1.5 \text{ to } 2.5 \text{ V (} V_{DS} = 10 \text{ V, } I_D = 1 \text{ mA)}$

Absolute Maximum Ratings (Ta = 25°C)

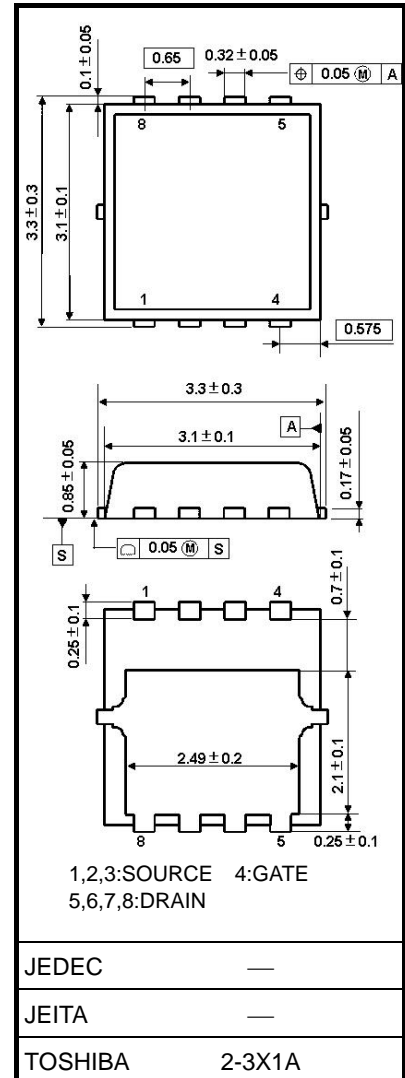
Characteristic		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	30	V
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		V_{DGR}	30	V
Gate-source voltage		V_{GSS}	± 20	V
Drain current	DC (Note 1)	I_D	22	A
	Pulsed (Note 1)	I_{DP}	66	
Drain power dissipation ($T_c = 25$)		P_D	30	W
Drain power dissipation ($t = 10 \text{ s}$) (Note 2a)		P_D	1.9	W
Drain power dissipation ($t = 10 \text{ s}$) (Note 2b)		P_D	0.7	W
Single-pulse avalanche energy (Note 3)		E_{AS}	126	mJ
Avalanche current		I_{AR}	22	A
Repetitive avalanche energy ($T_c = 25$) (Note 4)		E_{AR}	2.1	mJ
Channel temperature		T_{ch}	150	°C
Storage temperature range		T_{stg}	-55 to 150	°C

Note: For Notes 1 to 4, refer to the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

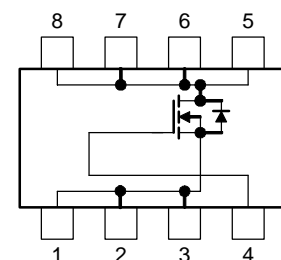
This transistor is an electrostatic-sensitive device. Handle with care.

Unit: mm



Weight: 0.02 g (typ.)

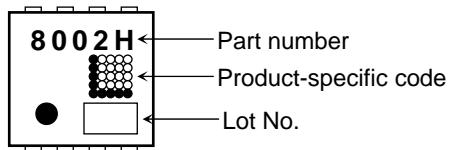
Circuit Configuration



Thermal Characteristics

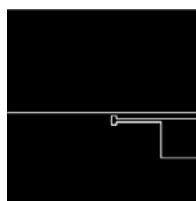
Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case ($T_c = 25$)	$R_{th(ch-c)}$	4.2	$^{\circ}C/W$
Thermal resistance, channel to ambient ($t = 10$ s) (Note 2a)	$R_{th(ch-a)}$	66	$^{\circ}C/W$
Thermal resistance, channel to ambient ($t = 10$ s) (Note 2b)	$R_{th(ch-a)}$	180	$^{\circ}C/W$

Marking (Note 5)



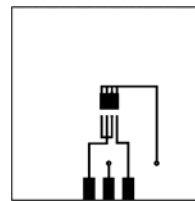
Note 1: Ensure that the channel temperature does not exceed $150^{\circ}C$.

Note 2: (a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)



(a)

FR-4
 $25.4 \times 25.4 \times 0.8$
 (Unit: mm)



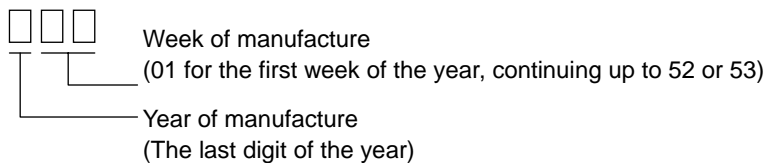
(b)

FR-4
 $25.4 \times 25.4 \times 0.8$
 (Unit: mm)

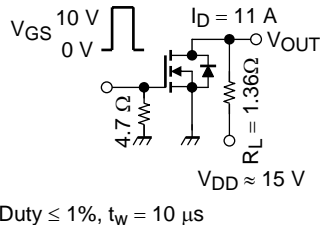
Note 3: $V_{DD} = 24$ V, $T_{ch} = 25^{\circ}C$ (initial), $L = 200$ μH , $R_G = 25$ Ω , $I_{AR} = 22$ A

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

Note 5: * Weekly code: (Three digits)

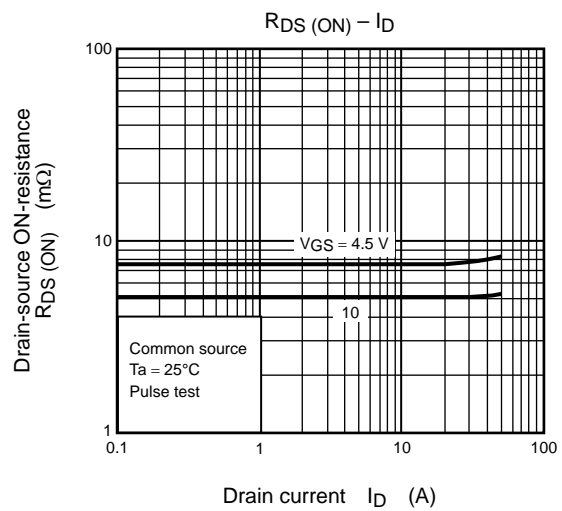
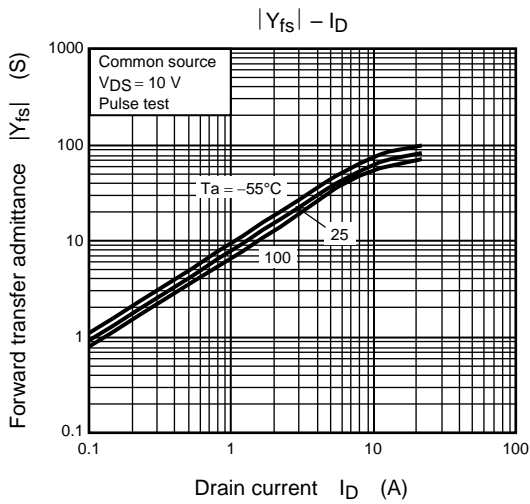
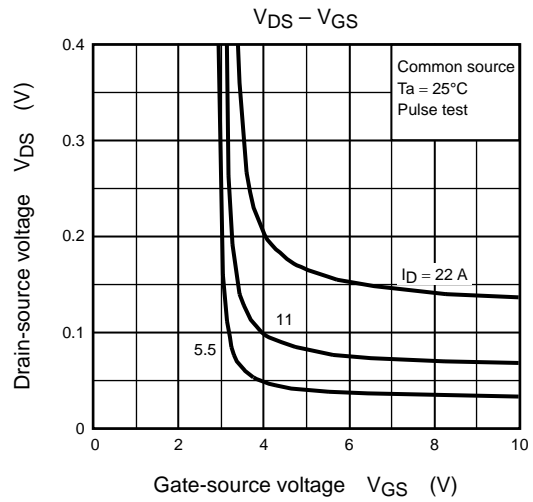
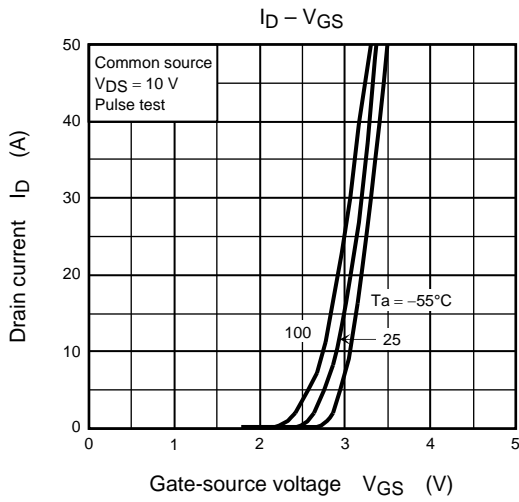
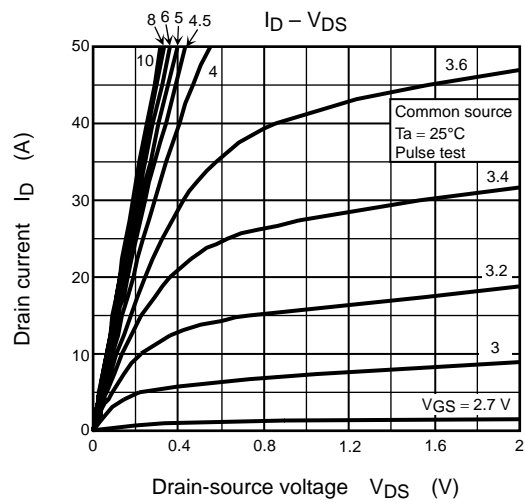
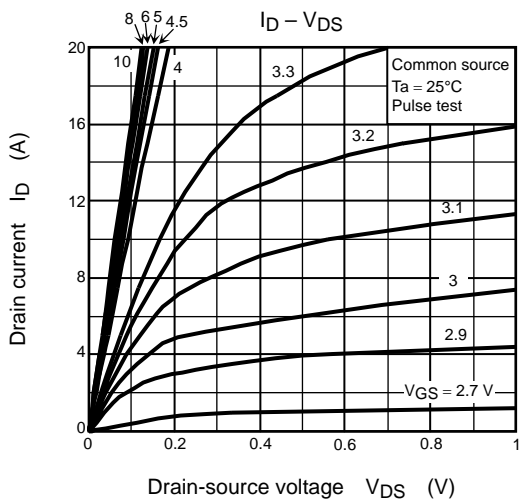


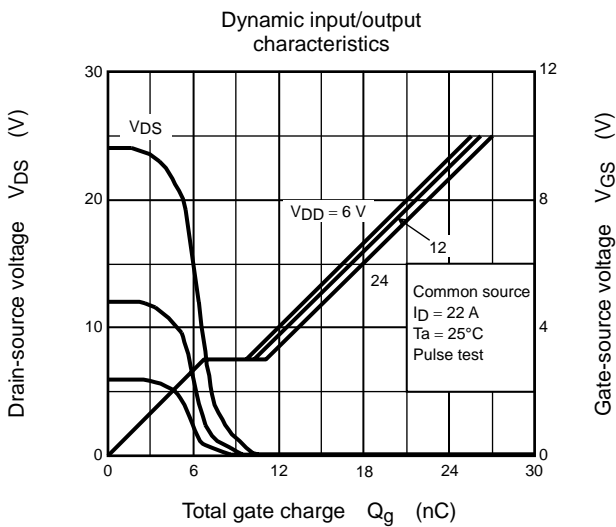
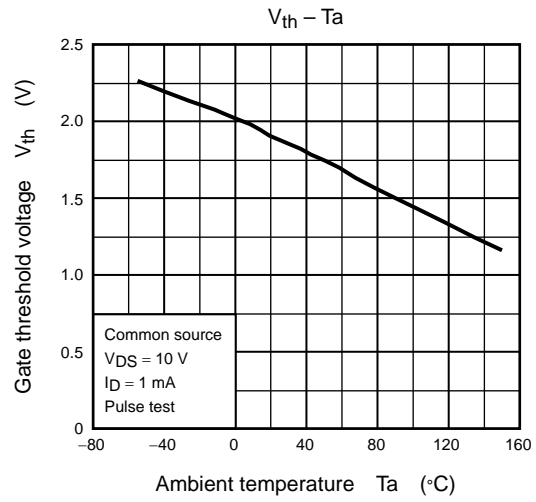
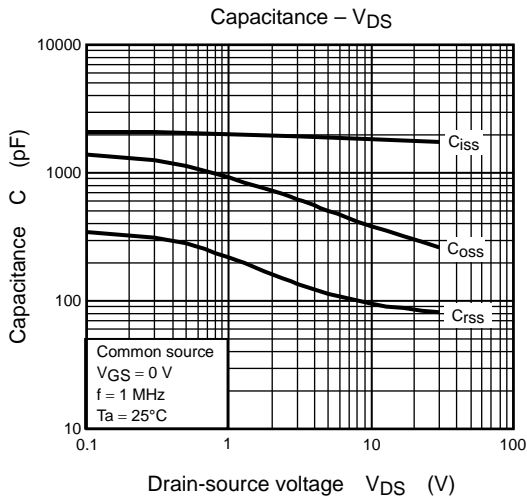
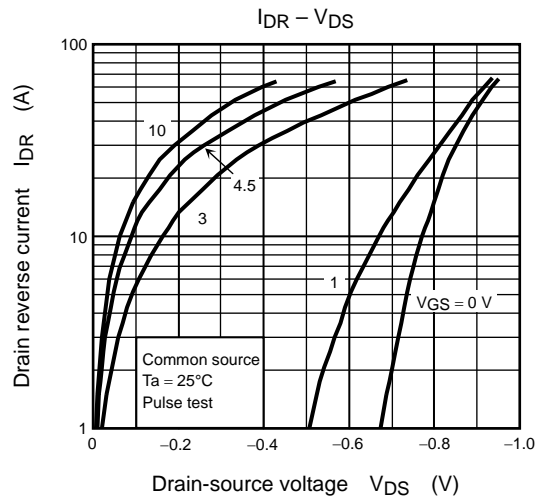
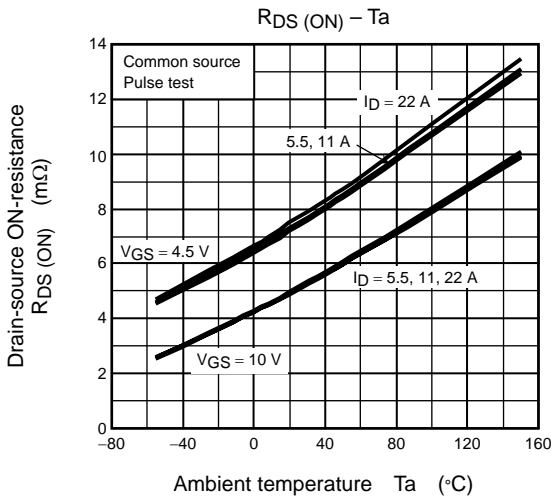
Electrical Characteristics (Ta = 25°C)

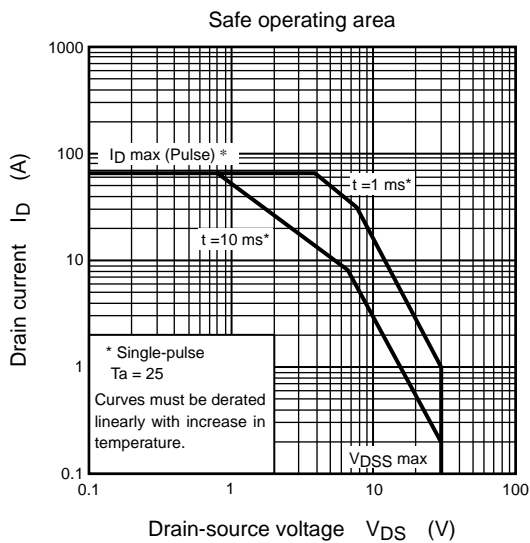
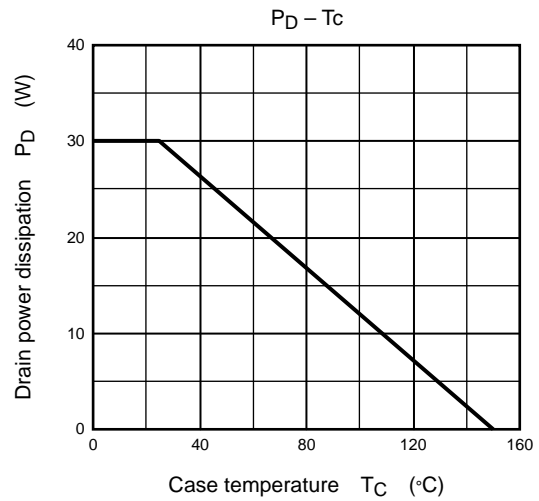
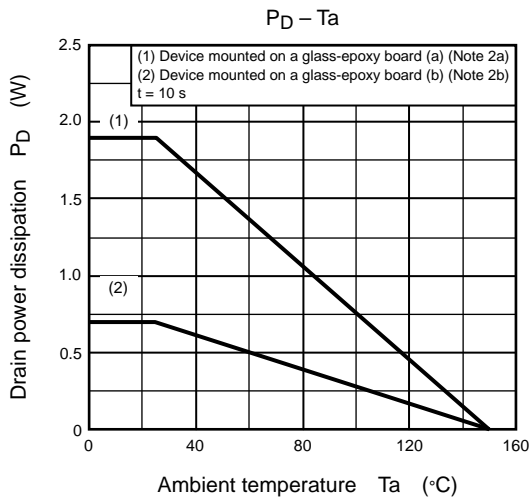
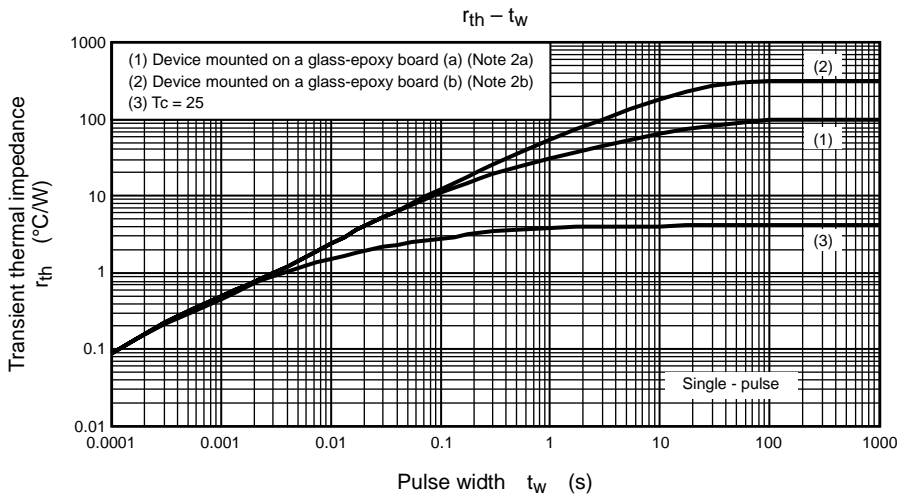
Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GSS}	$V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$	—	—	± 100	nA
Drain cutoff current		I_{DSS}	$V_{DS} = 30\text{ V}, V_{GS} = 0\text{ V}$	—	—	10	μA
Drain-source breakdown voltage		$V_{(BR)DSS}$	$I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$	30	—	—	V
		$V_{(BR)DSX}$	$I_D = 10\text{ mA}, V_{GS} = -20\text{ V}$	15	—	—	
Gate threshold voltage		V_{th}	$V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$	1.5	—	2.5	V
Drain-source ON-resistance		$R_{DS(ON)}$	$V_{GS} = 4.5\text{ V}, I_D = 11\text{ A}$	—	7.6	10.6	m Ω
			$V_{GS} = 10\text{ V}, I_D = 11\text{ A}$	—	5.5	8.3	
Forward transfer admittance		$ Y_{fs} $	$V_{DS} = 10\text{ V}, I_D = 11\text{ A}$	33	65	—	S
Input capacitance		C_{iss}	$V_{DS} = 10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	1900	2500	pF
Reverse transfer capacitance		C_{rss}		—	110	170	
Output capacitance		C_{oss}		—	400	—	
Gate resistance		r_g	$V_{DS} = 10\text{ V}, V_{GS} = 0\text{ V}, f = 5\text{ MHz}$	—	3.2	4.8	Ω
Switching time	Rise time	t_r	 <p>$V_{GS} = 10\text{ V}$ 0 V $I_D = 11\text{ A}$ V_{OUT} $4.7\ \Omega$ $R_L = 1.36\ \Omega$ $V_{DD} \approx 15\text{ V}$ Duty $\leq 1\%$, $t_w = 10\ \mu\text{s}$</p>	—	3.9	—	ns
	Turn-on time	t_{on}		—	11.7	—	
	Fall time	t_f		—	9.6	—	
	Turn-off time	t_{off}		—	39	—	
Total gate charge (gate-source plus gate-drain)		Q_g	$V_{DD} \approx 24\text{ V}, V_{GS} = 10\text{ V}, I_D = 22\text{ A}$	—	27	—	nC
			$V_{DD} \approx 24\text{ V}, V_{GS} = 5\text{ V}, I_D = 22\text{ A}$	—	14.3	—	
Gate-source charge 1		Q_{gs1}	$V_{DD} \approx 24\text{ V}, V_{GS} = 10\text{ V}, I_D = 22\text{ A}$	—	6.8	—	
Gate-drain ("Miller") charge		Q_{gd}		—	4.3	—	
Gate switch charge		Q_{sw}		—	7.1	—	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Drain reverse current	Pulse (Note 1)	I_{DRP}	—	—	—	66	A
Forward voltage (diode)		V_{DSF}	$I_{DR} = 22\text{ A}, V_{GS} = 0\text{ V}$	—	—	-1.2	V







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